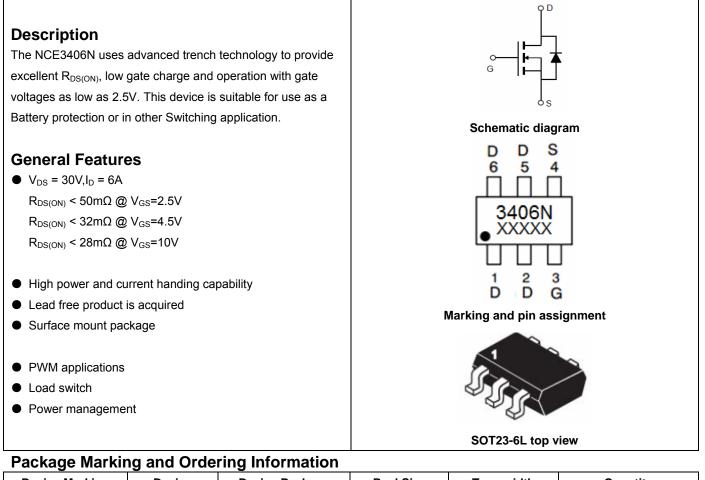


# NCE N-Channel Enhancement Mode Power MOSFET



Device Marking	Device	Device Package	Reel Size	Tape width	Quantity	
3406N	NCE3406N	SOT23-6L	Ø180mm	8 mm	3000 units	

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

5 ( )			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I <sub>D</sub>	6	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	30	A
Maximum Power Dissipation	PD	2.0	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C
Thermal Characteristic		•	•

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	62.5	°C/W

### **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±12V, $V_{DS}$ =0V	-	-	±100	nA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	0.7	0.9	1.4	V
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	27	50	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	24	32	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =6A	-	20.5	28	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =6A	10	-	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C <sub>lss</sub>		-	820	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V,	-	99	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	77	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	3.3	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =15V, R <sub>L</sub> =2.5 $\Omega$	-	4.8	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	26	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =15V,I <sub>D</sub> =6A,	-	9.5	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	$V_{GS}$ =4.5V	-	3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =6A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	6	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production



## **Typical Electrical and Thermal Characteristics**

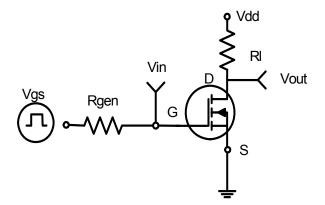


Figure 1:Switching Test Circuit

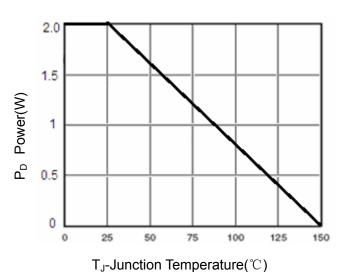
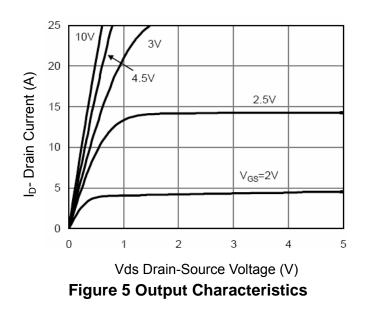


Figure 3 Power Dissipation



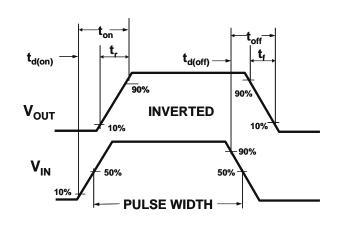
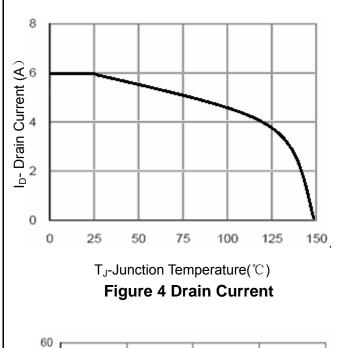


Figure 2:Switching Waveforms



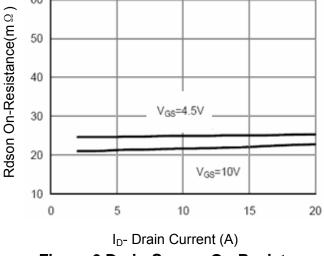


Figure 6 Drain-Source On-Resistance



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# NCE3406N

V<sub>GS</sub>=10∨

125

150

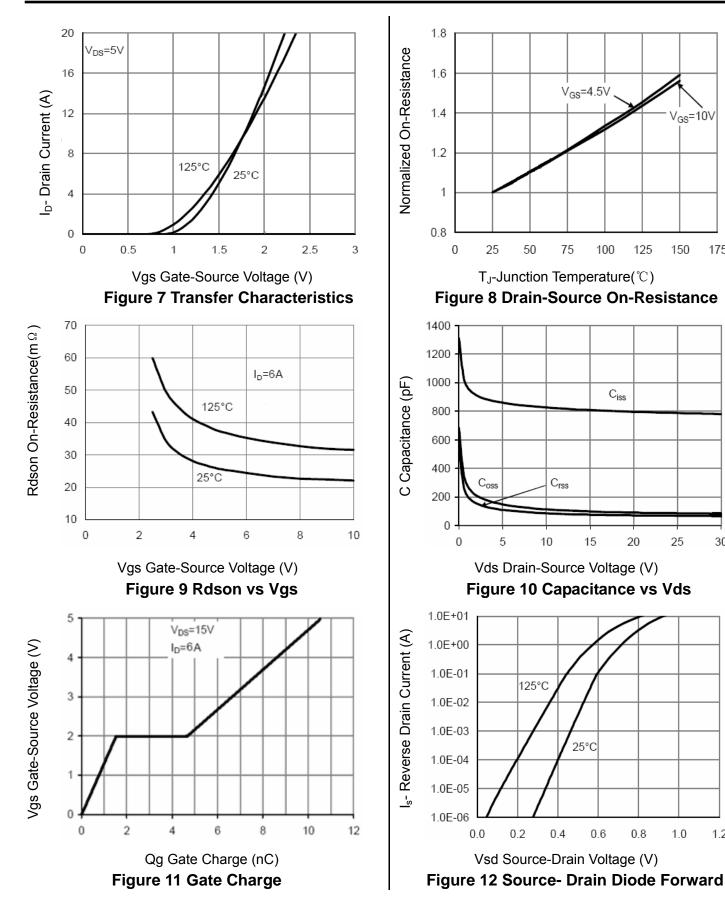
25

1.0

1.2

30

175





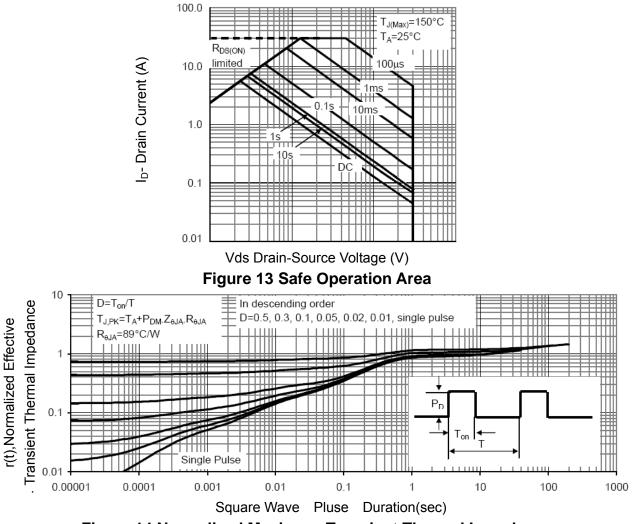
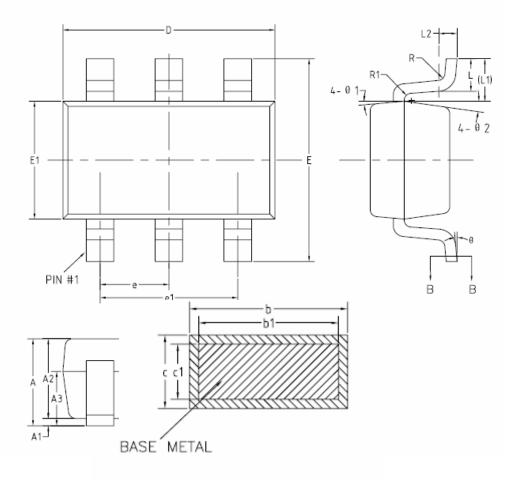


Figure 14 Normalized Maximum Transient Thermal Impedance



## SOT23-6L Package Information

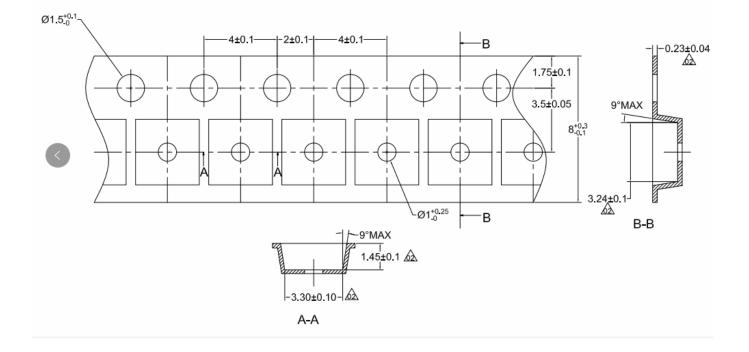


SYMBOL	MIN	NOM	MAX
A	-	-	1.45
A1	0	—	0.15
A2	0.90	1.10	1.30
A3	0.60	0.65	0.70
b	0.39	—	0.49
b1	0.38	0.40	0.45
с	0.12	-	0.19
c1	0.11	0.13	0.15
D	2.85	2.95	3.05
E	2.60	2.80	3.00
E1	1.55	1.65	1.75
е	0.85	0.95	1.05
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1		0.59REF	
L2		0.25BSC	
R	0.05	-	-
R1	0.05	-	0.20
θ	0*	-	8'
θ 1	8*	10°	12*
θ2	8*	10°	12°

#### COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)



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